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Renesas Electronics website: http://www.renesas.com

April 1st, 2010 Renesas Electronics Corporation

Issued by: Renesas Electronics Corporation (http://www.renesas.com)

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NPN SILICON RF TRANSISTOR **2SC5754**

NPN SILICON RF TRANSISTOR FOR MEDIUM OUTPUT POWER AMPLIFICATION (0.4 W) FLAT-LEAD 4-PIN THIN-TYPE SUPER MINIMOLD (M04)

FEATURES

- · Ideal for 460 MHz to 2.4 GHz medium output power amplification
- $P_{O (1 dB)} = 26.0 \text{ dBm TYP}$. @ $V_{CE} = 3.6 \text{ V}$, f = 1.8 GHz, Pin = 15 dBm
- High collector efficiency: $\eta c = 60\%$
- UHS0-HV technology (fT = 25 GHz) adopted
- High reliability through use of gold electrodes
- Flat-lead 4-pin thin-type super minimold (M04) package

ORDERING INFORMATION

Part Number	Quantity	Supplying Form	
2SC5754	50 pcs (Non reel)	• 8 mm wide embossed taping	
2SC5754-T2	3 kpcs/reel	• Pin 1 (Emitter), Pin 2 (Collector) face the perforation side of the tape	

Remark To order evaluation samples, contact your nearby sales office. The unit sample quantity is 50 pcs.

Caution Observe precautions when handling because these devices are sensitive to electrostatic discharge.

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ABSOLUTE MAXIMUM RATINGS (TA = +25°C)

Parameter	Symbol	Ratings	Unit
Collector to Base Voltage	Vсво	13	V
Collector to Emitter Voltage	Vceo	5.0	V
Emitter to Base Voltage	Vево	1.5	V
Collector Current	lc	500	mA
Total Power Dissipation	Ptot Note	735	mW
Junction Temperature	Tj	150	°C
Storage Temperature	Tstg	-65 to +150	°C

Note Mounted on 38×38 mm, t = 0.4 mm polyimide PCB

THERMAL RESISTANCE

*

	Parameter	Symbol	Test Conditions	Ratings	Unit
ł	Junction to Ambient Resistance	Rth j-a1	Mounted on 38×38 mm, t = 0.4 mm polyimide PCB	170	°C/W
		Rth j-a2	Stand alone device in free air	570	°C/W

ELECTRICAL CHARACTERISTICS (TA = +25°C)

Parameter	Symbol	Test Conditions	MIN.	TYP.	MAX.	Unit	
DC Characteristics	DC Characteristics						
Collector Cut-off Current	Ісво	Vсв = 5 V, IE = 0 mA	_	-	1 000	nA	
Emitter Cut-off Current	Ево	VBE = 1 V, IC = 0 mA	_	_	1 000	nA	
DC Current Gain	hfe ^{Note 1}	Vce = 3 V, Ic = 100 mA	40	60	100	_	
RF Characteristics	RF Characteristics						
Gain Bandwidth Product	f⊤	Vce = 3 V, Ic = 100 mA, f = 0.5 GHz	16	20	-	GHz	
Insertion Power Gain	S _{21e} ²	Vce = 3 V, Ic = 100 mA, f = 2 GHz	5.0	6.5	-	dB	
Reverse Transfer Capacitance	Cre ^{Note 2}	Vсв = 3 V, IE = 0 mA, f = 1 MHz	_	1.0	1.5	pF	
Maximum Available Power Gain	MAG Note 3	Vce = 3 V, Ic = 100 mA, f = 2 GHz	_	12.0	-	dB	
Linear Gain	G∟	$ V_{CE} = 3.6 \ V, \ I_{Cq} = 20 \ mA, \ f = 1.8 \ GHz, \\ P_{in} = 0 \ dBm, \ 1/2 \ Duty $	-	12.0	-	dB	
Gain 1 dB Compression Output Power	Po (1 dB)	$ V_{CE} = 3.6 \text{ V}, \ I_{Cq} = 4 \text{ mA}, \ f = 1.8 \text{ GHz}, \\ P_{in} = 15 \text{ dBm}, \ 1/2 \text{ Duty} $	-	26.0	-	dBm	
Collector Efficiency	ης	$ V_{CE} = 3.6 \text{ V}, \ I_{Cq} = 4 \text{ mA}, \ f = 1.8 \text{ GHz}, \\ P_{in} = 15 \text{ dBm}, \ 1/2 \text{ Duty} $	-	60	-	%	

Notes 1. Pulse measurement: PW \leq 350 μ s, Duty Cycle \leq 2%

2. Collector to base capacitance when the emitter grounded

3. MAG =
$$\left| \frac{S_{21}}{S_{12}} \right| (K - \sqrt{(K^2 - 1)})$$

hfe CLASSIFICATION

Rank	FB	
Marking	R57	
hfe Value	40 to 100	

f = 1 MHz

3

4 mA

3

3 mA

4

4

I_B : 0.5 mA step

2 mA

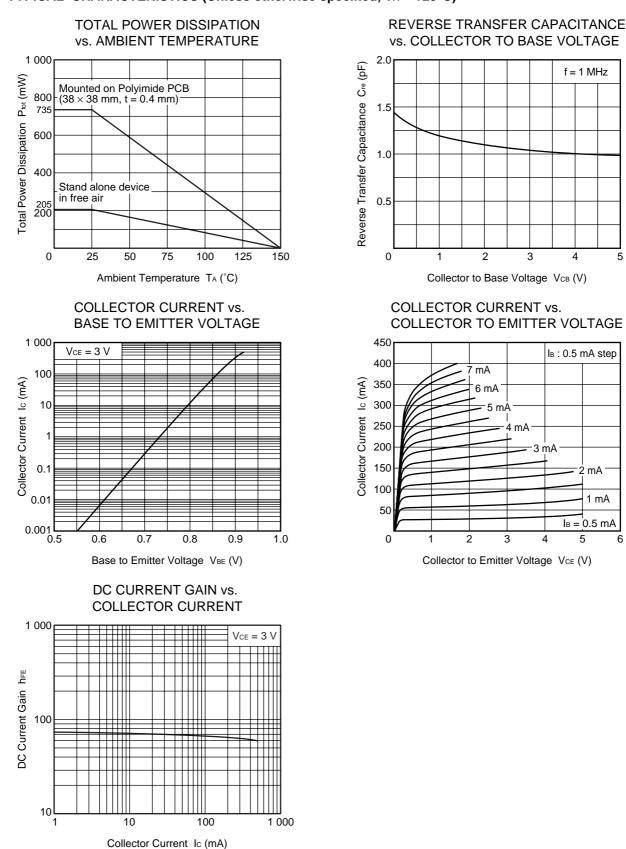
l_B = 0.5 mA

5

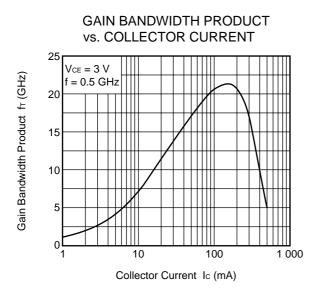
1 mA

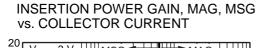
6

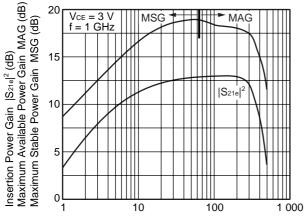
5



TYPICAL CHARACTERISTICS (Unless otherwise specified, $T_A = +25^{\circ}C$)

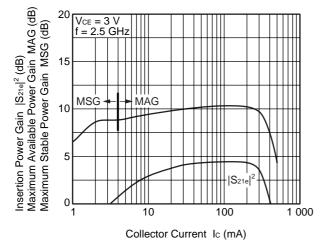


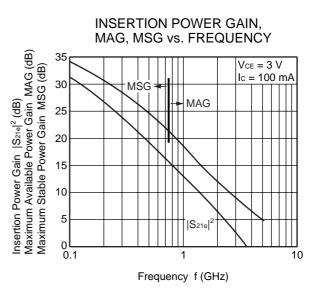




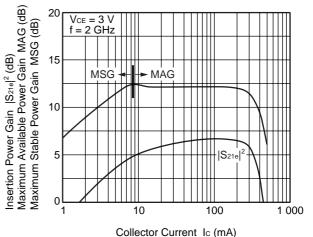
Collector Current Ic (mA)

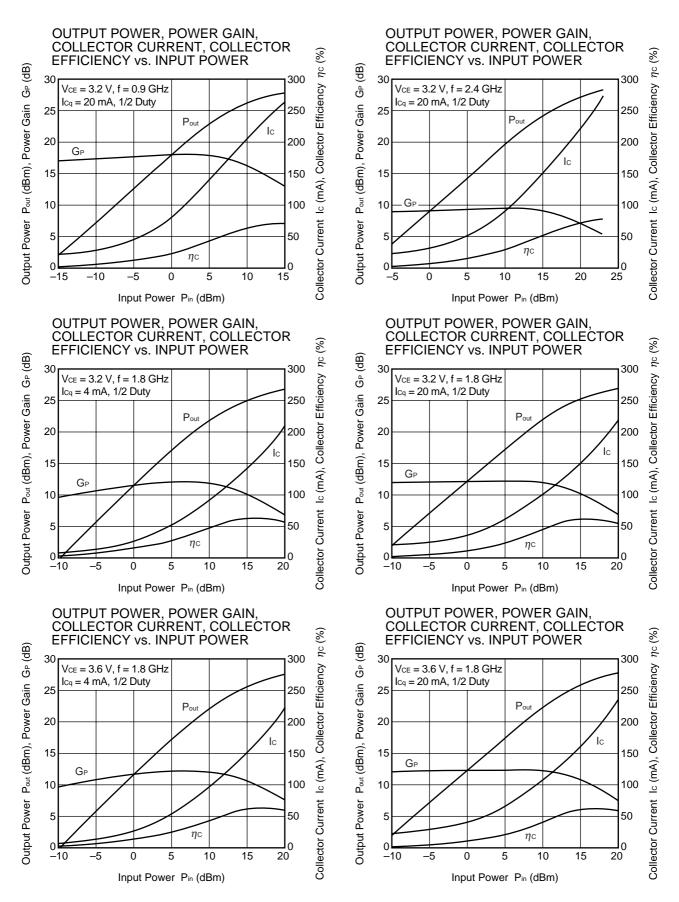
INSERTION POWER GAIN, MAG, MSG vs. COLLECTOR CURRENT





INSERTION POWER GAIN, MAG, MSG vs. COLLECTOR CURRENT



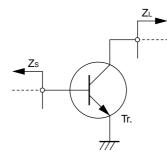


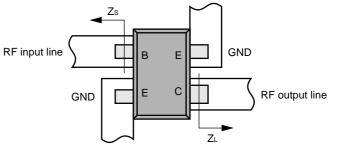
Remark The graphs indicate nominal characteristics.

Data Sheet PU10008EJ02V0DS

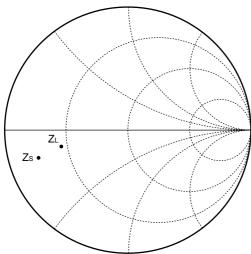
Frequency f (GHz)	Collector to Emitter Voltage Vce (V)	Supply Impedance Zs (Ω)	Load Impedance Ζ∟ (Ω)
0.9	2.8 to 3.6	8.4 – 5.2 j	15.1 – 4.3 j
1.8	2.8 to 3.6	6.3 – 16.4 j	15.8 – 6.9 j
2.4	2.8 to 3.6	5.9 – 22.1 j	15.2 – 17.9 j

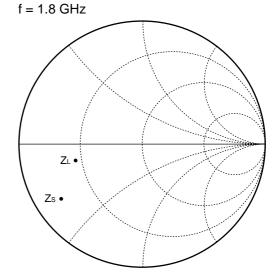
POWER SUPPLY IMPEDANCE, LOAD IMPEDANCE (Recommended value)



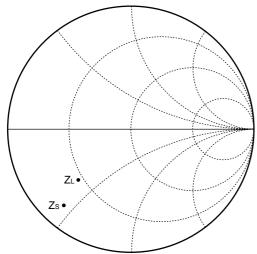


f = 0.9 GHz

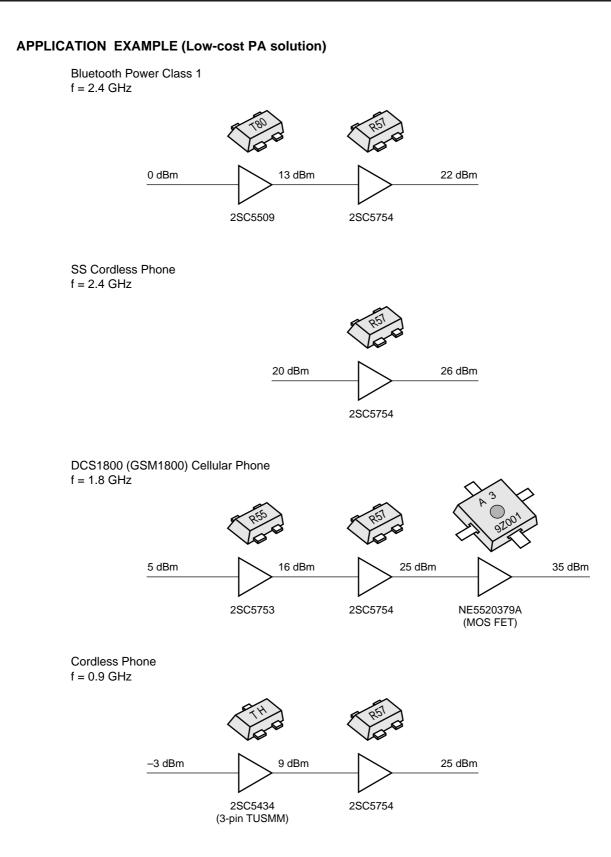




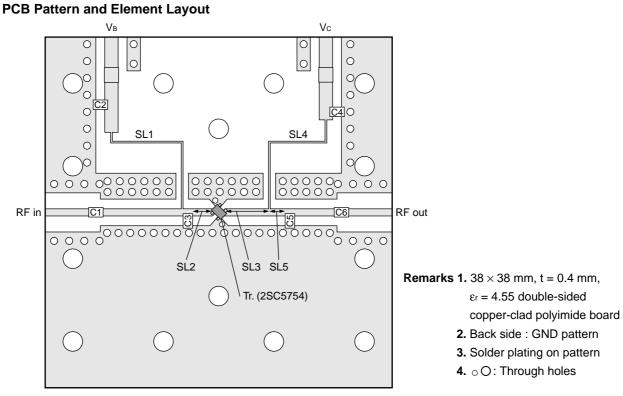
f = 2.4 GHz



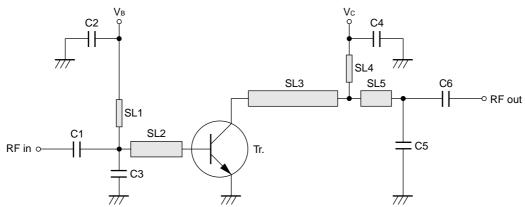
Data Sheet PU10008EJ02V0DS



EVALUATION CIRCUIT EXAMPLE: 1.8 GHz PA EVALUATION BOARD

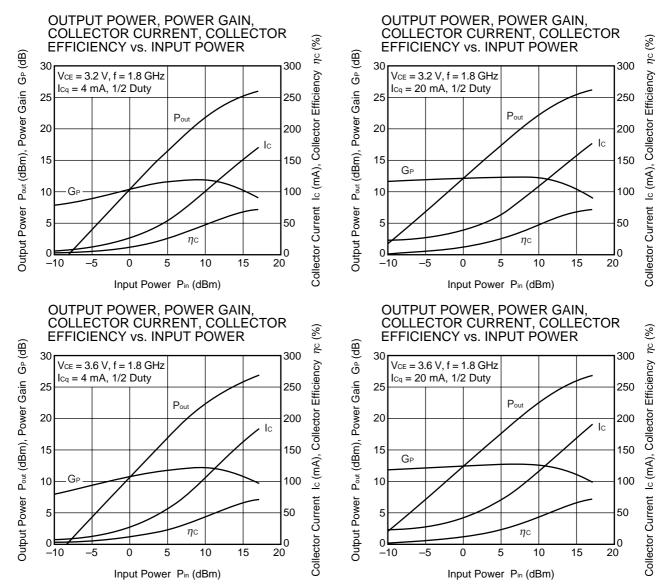


Equivalent Circuit



Parts List

Parts	Value	Size	Classification
C1, C6	18 pF		Multiplayer ceramic chip capacitor
C2	3 300 pF		Multiplayer ceramic chip capacitor
C3	3 pF		Multiplayer ceramic chip capacitor
C4	15 pF		Multiplayer ceramic chip capacitor
C5	1.5 pF		Multiplayer ceramic chip capacitor
SL1, SL4		w = 0.20 mm	Strip line
SL2		w = 0.76 mm, l = 2.5 mm	Strip line
SL3		w = 0.76 mm, l = 5 mm	Strip line
SL5		w = 0.76 mm, l = 1.5 mm	Strip line



EXAMPLE OF CHARACTERISTICS FOR 1.8 GHz PA EVALUATION BOARD



S-PARAMETERS

S-parameters/Noise parameters are provided on the NEC Compound Semiconductor Devices Web site in a form (S2P) that enables direct import to a microwave circuit simulator without keyboard input.

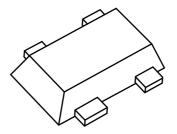
Click here to download S-parameters.

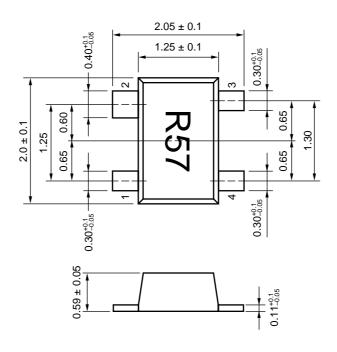
 $[\mathsf{RF} \text{ and Microwave}] \rightarrow [\mathsf{Device Parameters}]$

URL http://www.csd-nec.com/

PACKAGE DIMENSIONS

FLAT-LEAD 4-PIN THIN-TYPE SUPER MINIMOLD (M04) (UNIT: mm)





PIN CONNECTIONS

- 1. Emitter
- 2. Collector
- 3. Emitter
- 4. Base

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